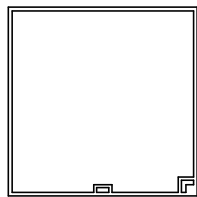
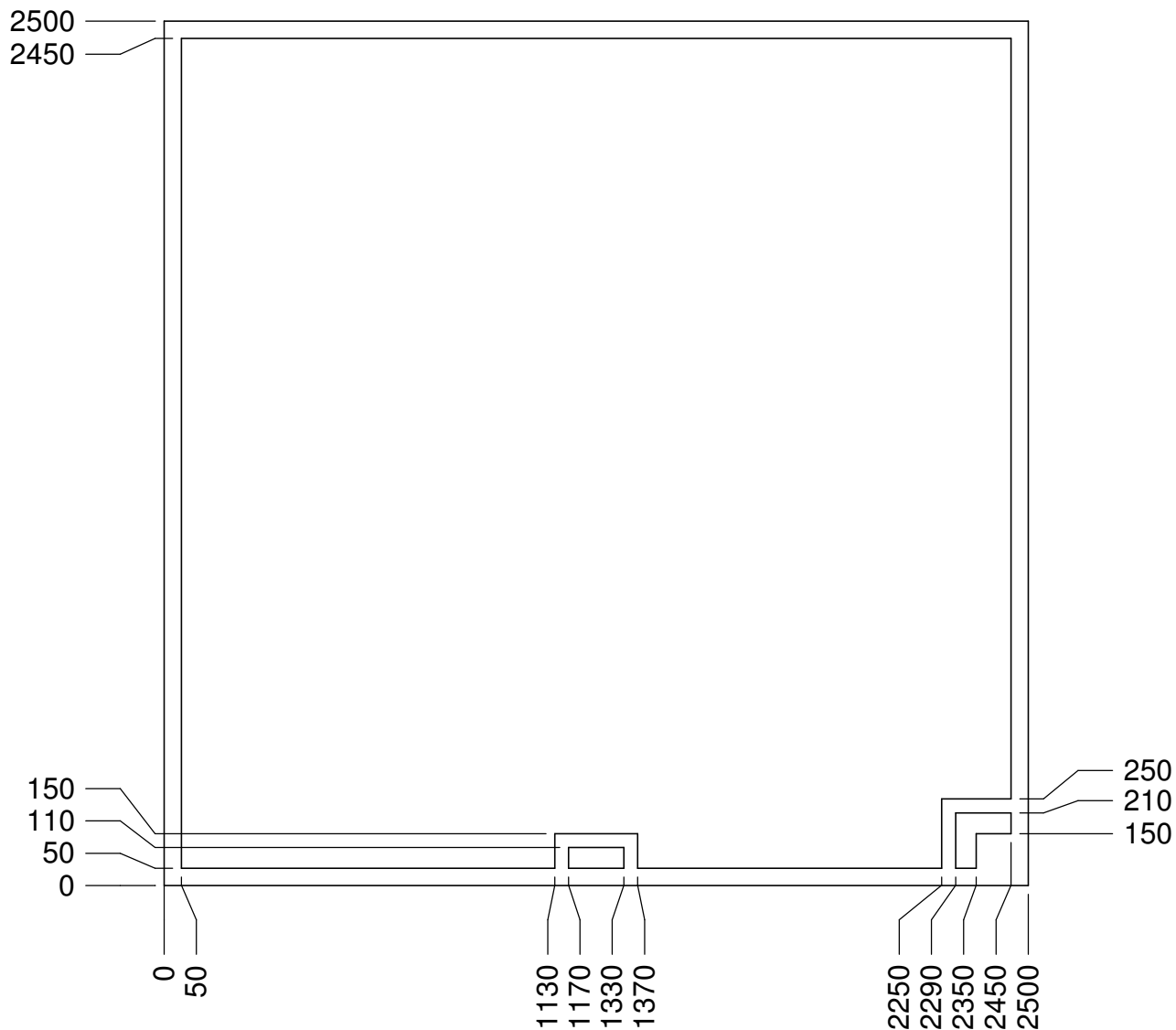


REVISIONS				
DATE	REV.	ECO	DESCRIPTION	APPROVED



SCALE 10:1

Notes: (Unless Otherwise Specified).

- 1) DIE MATERIAL IS SILICON.
- 2) DIE THICKNESS IS 250 um (10 MIL).
- 3) METALLIZATION 1.0 um ALUMINUM (Al) OVER 0.75 um SiO₂.
- 4) DIE IS WITHOUT PASSIVATION.
- 5) WIRE BONDABLE WITH GOLD (Au) OR ALUMINUM (Al) WIRE.
- 6) DIFFERENTIAL PAIR (2 PADS) WITH LARGE GROUND PAD.
- 7) RF / MICROWAVE PARASITIC TEST APPLICATIONS.
- 8) TOLERANCE = ± 1 um.

DIMENSIONS IN MICRONS
1000 um = 1.0mm

PART NUMBER SYSTEM					
TD	-	2	-	2.5	- DIF
SILICON TEST DIE	BOND PADS	DIE SIZE (mm)	DIFFERENTIAL PAIR		

TOLERANCE UNLESS NOTED		APPROVALS	DATE				
X.XX	+/- 0.01	DRAWN J. HINES	5/8/2010	TITLE Si TEST DIE TD SERIES			
X.XXX	+/- 0.005						
X.XXXX	+/- 0.0005						
ANGLES	+/- 0.5°	ENG		SCALE	SIZE	DRAWING NO.	REV
ALL DIMENSIONS IN		MFG		50:1	A	152502	A
<input checked="" type="checkbox"/> INCHES <input type="checkbox"/> MILLIMETERS		QA		DO NOT SCALE DRAWING SHEET 1 OF 1			
THIRD ANGLE PROJECTION		CUST					
		REVISED					